

4V Drive Nch MOS FET

RSQ045N03

●Structure

Silicon N-channel MOS FET

●Features

- 1) Low On-resistance.
- 2) Space saving, small surface mount package (TSMT6).
- 3) Low voltage drive (4V drive).

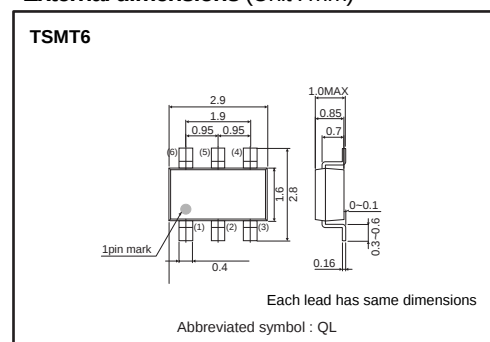
●Applications

Switching

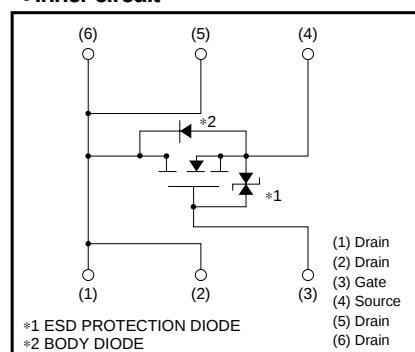
●Packaging specifications

Type	Package	Taping
	Code	TR
RSQ045N03	Basic ordering unit (pieces)	3000
		○

●External dimensions (Unit : mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DS}	30	V
Gate-source voltage		V_{GS}	20	V
Drain current	Continuous	I_D	± 4.5	A
	Pulsed	I_{DP} *1	± 18	A
Source current (Body diode)	Continuous	I_S	1.0	A
	Pulsed	I_{SP} *1	18	A
Total power dissipation		P_D *2	1.25	W
Channel temperature		T_{ch}	150	°C
Range of storage temperature		T_{stg}	-55 to +150	°C

*1 $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$

*2 Mounted on a ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}$ *	100	°C/W

* Mounted on a ceramic board

Transistors

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	—	—	10	μA	$V_{GS}=20V, V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR) DSS}$	30	—	—	V	$I_D=1mA, V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS}=30V, V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	1.0	—	2.5	V	$V_{DS}=10V, I_D=1mA$
Static drain-source on-state resistance	$R_{DS(on)}$ *	—	27	38	$m\Omega$	$I_D=4.5A, V_{GS}=10V$
		—	36	51	$m\Omega$	$I_D=4.5A, V_{GS}=4.5V$
		—	40	56	$m\Omega$	$I_D=4.5A, V_{GS}=4V$
Forward transfer admittance	$ Y_{fs} $ *	3.5	—	—	S	$V_{DS}=10V, I_D=4.5A$
Input capacitance	C_{iss}	—	520	—	pF	$V_{DS}=10V$
Output capacitance	C_{oss}	—	150	—	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	—	95	—	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}$ *	—	12	—	ns	$V_{DD}=15V$
Rise time	t_r *	—	19	—	ns	$I_D=2.25A$
Turn-off delay time	$t_{d(off)}$ *	—	41	—	ns	$V_{GS}=10V$
Fall time	t_f *	—	14	—	ns	$R_L=6.67\Omega$
Total gate charge	Q_g *	—	6.8	9.5	nC	$V_{DD}=15V, V_{GS}=5V$
Gate-source charge	Q_{gs} *	—	1.6	—	nC	$I_D=4.5A$
Gate-drain charge	Q_{gd} *	—	2.3	—	nC	$R_L=3.33\Omega, R_G=10\Omega$

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}	—	—	1.2	V	$I_S=1.0A, V_{GS}=0V$

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